

# S25FL008A

## CS 80642

**Qualification of: S25FL008A, 8-Megabit 3.0 Volt Flash Memory with 50 MHz SPI Bus Interface in SOC008 (8.00 x 5.28 x 2.159mm) 8 Lead, Small Outline Integrated Circuit (SOIC)**



### Reliability Qualification Summary

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Additionally, the package details (material set, assembly location, etc.) are specific to the qual vehicle used for the qualification. Alternate material sets and assembly locations may be qualified for the product. Production material can be assembled with any qualified material set and at any qualified assembly location. Tests are performed in accordance with AEC-Q100 and relevant JEDEC specifications.

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## I. Product Information

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Product Description: S25FL008A  
8-Megabit 3.0 Volt Flash Memory with 50 MHz SPI Bus Interface

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Package:	SOC008	Qualification:	80642
Description:	(8.00 x 5.28 x 2.159mm) 8 Lead, Small Outline Integrated Circuit (SOIC)		
Theta Ja:	75 °C/W	Psi Jt:	15 °C/W
Assembly Location:	Stats ChipPAC Shanghai	Molding Compound:	RoHS Compliant Epoxy Resin
Substrate/Leadframe:	Copper Leadframe	Die Attachment:	Paste
Lead Finish:	100% Matte Sn Plating	Bond Wire:	Gold
Comments:			

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Est. Field Temperature:	55 °C	Life Test Temperature:	150 °C
Est. DC Field Current:	25 mA	Life Test Dynamic Current:	4 mA
Est. Field Voltage:	3.0 V	Life Test Voltage:	3.6 V
Est. Field Power Dissipation:	75 mWatts	Est. Stress Power Dissipation:	14.4 mWatts
Est. Field Tj:	60.6 °C	Est. Stress Tj:	151.0 °C

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Die:	98GZ1A	Die Size:	3.33 x 4.20 mm
Process:	CS99S (200nm)	Fab:	Spansion Monden
Type:	MirrorBit	Density:	8M

## II. CS99S Life Test Failure Rate Calculation

HTOL Stress Temperature - 150 °C

Failure Mechanism	Read Points / Test Results				Modeling Parameters @ 55°C					Avg. Failure Rate FITS @ 55°C, 60% Conf.	
	24 hrs	168 hrs	504 hrs	1000 hrs	Ea eV	TAF	VAF	OAF	MTTF (yrs)	Early Life	Inherent Life
PLASTIC											
Sample Size	2662	2542	965	462							
Zero fails, Process ave. Ea	0 *	0	0	0	0.66	158	1	158		84	8
Totals	0	0	0	0					19026	84	6

\* - Contributes to early life FITS

Data Retention Bake - 150 °C

Reliability Stress	Number of Rejects	Sample Size	Failure Rate %	Failure Mechanism
500 hrs	0	731	0.00	No Failures
1000 hrs	0	479	0.00	No Failures
2000 hrs	0	326	0.00	No Failures

### III. Summary of Stress Test Results

Stress Test	Stress Condition	Package Type	Sample Size	Num. of Lots	Num. of Fails	Failure Rate %	Comments
Data From Qualification 80642:							
HTOL (EL)	(3.6V, 150°C)	SOC008 <sup>1</sup>	144	3	0	0.00	168 hours
ESD CDM	N/A	SOC008 <sup>1</sup>	45	3	0	0.00	Passed 1.0kV
ESD HBM	(100pF, 1500 Ohms)	SOC008 <sup>1</sup>	180	3	0	0.00	Passed 2.0kV
Latch Up	(125°C, +/- 100mA)	SOC008 <sup>1</sup>	18	3	0	0.00	Passed
Endurance (10k)	(90°C, 3.6V)	SOC008 <sup>1</sup>	96	1	0	0.00	10k cycles
Preconditioning	(PC1/260°C, +0°C/-5°C)	SOC008 <sup>1</sup>	693	3	0	0.00	Passed Jedec L3 / Jeita Rank E
Precon+Temp Cycle	(PC1/260°C, -40°C/150°C)	SOC008 <sup>1</sup>	231	3	0	0.00	1000 cycles
Precon+HAST	(PC1/260°C, Biased, 130°C/85% RH)	SOC008 <sup>1</sup>	231	3	0	0.00	96 hours
Precon+Steam Pressure	(PC1/260°C, 121°C/100%RH/15PSIG)	SOC008 <sup>1</sup>	231	3	0	0.00	168 hours

Notes / Justification: 1) Results from Qual 80642, S25FL008A, 8M CS99S (200nm) MirrorBit in 8 Lead SOIC (8 x 5.28 x 2.159mm)

Preconditioning Flows: PC1 (Exceeds JEDEC L3 and JEITA Rank E): Bake 125°C, 24hr => Soak @ 30°C/70%RH, 216hr => 3x Reflow

## IV. Revision History

Section	Description
Revision A - 2/28/2006	Initial Release.

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